TOSHIBA Field Effect Transistor Silicon P Channel MOS Type(U-MOSVI)

# SSM6J501NU

#### **Power Management Switch Applications**

- 1.5V drive
- Low ON-resistance:  $R_{DS(ON)}$  = 43.0 m $\Omega$  (max) (@V<sub>GS</sub> = -1.5 V)
  - $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})}$  = 26.5 m $\Omega$  (max) (@V\_{GS} = -1.8 V)
  - $R_{DS(ON)}$  = 19.0 m $\Omega$  (max) (@V<sub>GS</sub> = -2.5 V)
  - $R_{DS(ON)}$  = 15.3 m $\Omega$  (max) (@V<sub>GS</sub> = -4.5 V)

#### Absolute Maximum Ratings (Ta = 25°C)

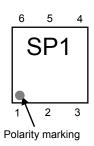
Charac	teristics	Symbol	Rating	Unit	
Drain-Source voltag	je	V <sub>DSS</sub>	-20	V	
Gate-Source voltage		V <sub>GSS</sub>	±8	V	
Drain current	DC	۱ <sub>D</sub>	-10	А	
	Pulse	I <sub>DP</sub> (Note 1)	<sub>DP</sub> (Note 1) –30		
Power dissipation		P <sub>D</sub> (Note 2)	1	w	
		t≦10s	2	vv	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature		T <sub>stg</sub>	–55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

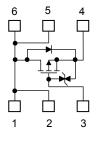
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

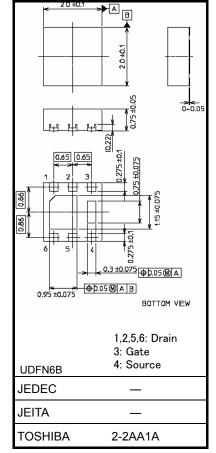
- Note 1: The pulse width limited by max channel temperature.
- Note 2: Mounted on an FR4 board.  $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{Cu Pad: 645 mm}^2)$

### Marking(Top View)



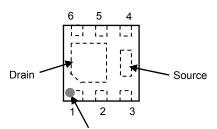
Equivalent Circuit(Top View)





Weight: 8.5 mg (typ.)

#### Pin Condition(Top View)



Polarity marking (on the top) \*Electrodes : on the bottom

Start of commercial production 2010-11

Unit: mm

#### **Electrical Characteristics (Ta = 25°C)**

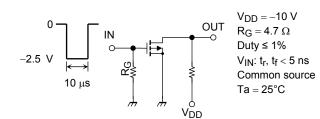
Chara	acteristic	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain Source brookdown voltage	kdown voltago	V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$ -20		-20		_	V
Drain-Source breakdown voltage		V (BR) DSX	$I_{D} = -1 \text{ mA}, V_{GS} = 5 \text{ V}$	-15		_	v	
Drain cut-off curre	nt	IDSS	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$				-1	μA
Gate leakage curr	ent	I <sub>GSS</sub>	$V_{GS} = \pm 8 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				±1	μA
Gate threshold vo	Itage	V <sub>th</sub>	$V_{DS} = -3 V, I_D = -1 mA$		-0.3	_	-1.0	V
Forward transfer a	admittance	Y <sub>fs</sub>	$V_{DS} = -3 V, I_D = -2.0 A$	(Note 3)	11	22	_	S
			$I_D = -4.0$ A, $V_{GS} = -4.5$ V	(Note 3)		12	15.3	
Drain–source ON-resistance		R <sub>DS (ON)</sub>	I <sub>D</sub> = -4.0 A, V <sub>GS</sub> = -2.5 V	(Note 3)		14	19	mΩ
			$I_D = -4.0 \text{ A}, \text{ V}_{GS} = -1.8 \text{ V}$	(Note 3)		17	26.5	
			$I_D = -2.0 \text{ A}, \text{ V}_{GS} = -1.5 \text{ V}$	(Note 3)		20	43	
Input capacitance		C <sub>iss</sub>				2600		
Output capacitance		C <sub>oss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz			290		pF
Reverse transfer capacitance		C <sub>rss</sub>		_	280	_		
Total Gate Charge		Qg	N 40.14 40.4		_	29.9	_	
Gate-Source Charge		Q <sub>gs1</sub>	V <sub>DD</sub> = -10 V, I <sub>D</sub> = -10 A - V <sub>GS</sub> = -4.5 V		_	3.0	_	nC
Gate-Drain Charge		Q <sub>gd</sub>			_	5.6	_	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = -10 \text{ V}, \text{ I}_{D} = -2.0 \text{ A},$			45.2	_	
	Turn-off time	toff	$V_{GS}$ = 0 to -2.5 V, $R_{G}$ = 4.7 $\Omega$			201	_	ns
Drain-Source forward voltage		V <sub>DSF</sub>	$I_D = 4 \text{ A}, \text{ V}_{GS} = 0 \text{ V} \qquad (\text{Note 3})$		_	0.70	1.1	V

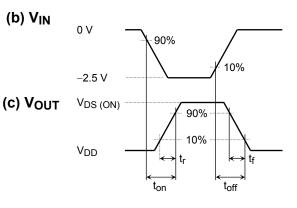
Note 3: Pulse test

Note 4: If a forward bias is applied between gate and source, this device enters V(BR)DSX mode. Note that the drain-source breakdown voltage is lowered in this mode

#### Switching Time Test Circuit

#### (a) Test circuit





#### Precaution

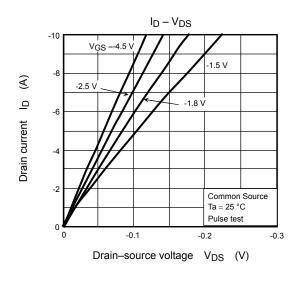
Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current (I<sub>D</sub>) to be low (-1 mA for the SSM6J501NU). Then, for normal switching operation,  $V_{GS(on)}$  must be higher than  $V_{th}$ , and  $V_{GS(off)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .

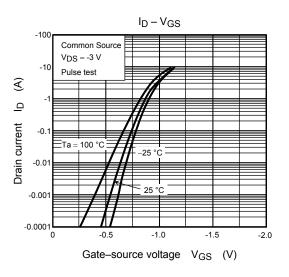
Take this into consideration when using the device.

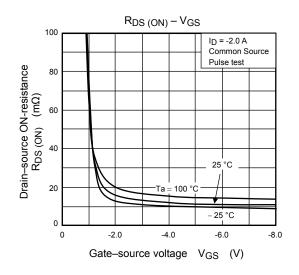
#### **Handling Precaution**

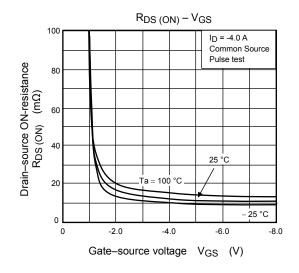
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

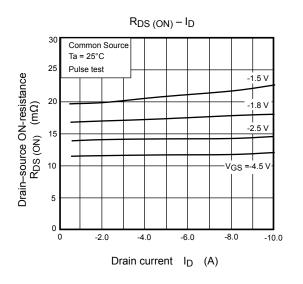
Thermal resistance  $R_{th (ch-a)}$  and power dissipation  $P_D$  vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

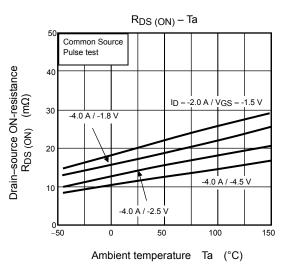


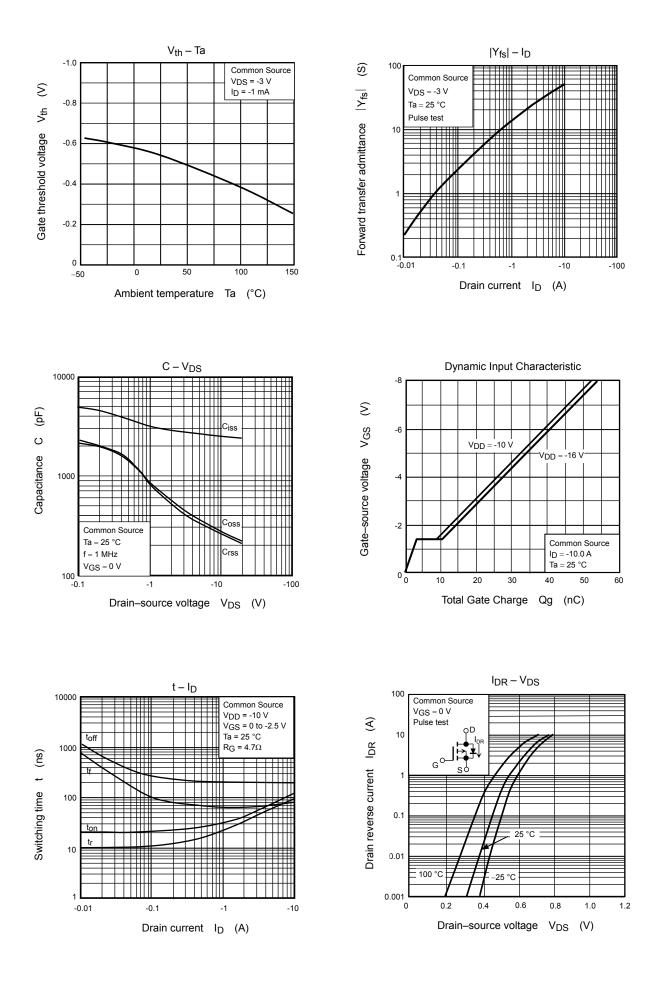




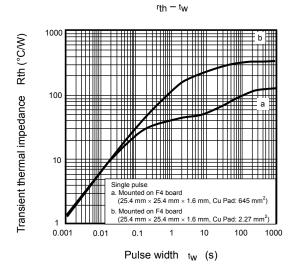


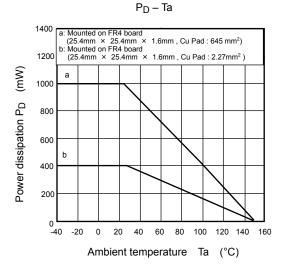






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